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Aims and Scope

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Original articles, communications, and selected reviews of broad interest will be considered for publication. Manuscripts may include illustrative material in color if this will enhance the presentation. There are no page charges and 25 free reprints will be supplied to the principal author. Regular papers may be sent to R. R. Holmes in Amherst or to L. Maier in Basel. Communications and reviews should be sent to W. Walter in Hamburg or J. G. Verkade in Ames.

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